TABLE OF CONTENTS

Features
Applications1
Typical Application Circuits1
General Description
Revision History 2
Specifications
Input and Output Capacitor, Recommended Specifications 4
Absolute Maximum Ratings
Thermal Data 5
Thermal Resistance
ESD Caution
Pin Configurations and Function Descriptions
Typical Performance Characteristics7
Theory of Operation

REVISION HISTORY

1/15—Rev. G to Rev. H
Changes to Ordering Guide 19
4/14—Rev. F to Rev. G
Changes to Figure 1 and Figure 21Changes to Figure 3 and Figure 46Updated Outline Dimensions19Changes to Ordering Guide19
8/13—Rev. E to Rev. F
Changes to Ordering Guide 19
6/13—Rev. D to Rev. E
Changed Adjustable Output Voltage Option with Soft Start (ADP1755) from 0.75 V to 3.0 V to 0.75 V to 3.3 V (Throughout)
12/12—Rev. C to Rev. D
Added Junction Temperature of 150°C, Table 3
9/12—Rev. B to Rev. C
Changes to Table 3
2/10—Rev. A to Rev. B
Changes to Table 45 Changes to Ordering Guide
4/09—Rev. 0 to Rev. A
Changes to Table 3

10/08—Revision 0: Initial Version

Soft Start Function	. 11
Adjustable Output Voltage (ADP1741)	. 12
Enable Feature	. 12
Power-Good Feature	. 12
Reverse Current Protection Feature	. 13
Applications Information	. 14
Capacitor Selection	. 14
Undervoltage Lockout	. 15
Current-Limit and Thermal Overload Protection	. 15
Thermal Considerations	. 15
PCB Layout Considerations	. 17
Outline Dimensions	. 19
Ordering Guide	. 19

SPECIFICATIONS

 $V_{IN} = (V_{OUT} + 0.4 \text{ V}) \text{ or } 1.6 \text{ V}$ (whichever is greater), $I_{OUT} = 100 \text{ mA}$, $C_{IN} = C_{OUT} = 4.7 \mu\text{F}$, $T_A = 25^{\circ}\text{C}$, unless otherwise noted.

Table 1.	
----------	--

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
INPUT VOLTAGE RANGE	V _{IN}	$T_{J} = -40^{\circ}C \text{ to } +125^{\circ}C$	1.6		3.6	V
OPERATING SUPPLY CURRENT ¹		Ιουτ = 500 μΑ		90		μΑ
		Ι _{ουτ} = 100 mA		400		μΑ
		I _{OUT} = 100 mA, T _J = -40°C to +125°C			800	μΑ
		Iout = 2 A		1.5		mA
		I _{OUT} = 2 A, T _J = -40°C to +125°C			1.8	mA
SHUTDOWN CURRENT	I _{GND-SD}	$EN = GND, V_{IN} = 3.6 V$		2	6	μΑ
		EN = GND, V _{IN} = 1.6 V, T _J = −40°C to +85°C			30	μΑ
		EN = GND, V _{IN} = 3.6 V, T _J = −40°C to +85°C			100	μΑ
OUTPUT VOLTAGE ACCURACY						
Fixed Output Voltage Accuracy	Vout	louτ = 100 mA	-1		+1	%
(ADP1740)		$I_{OUT} = 10 \text{ mA to } 2 \text{ A}$	-1.5		+1.5	%
		10 mA < I _{OUT} < 2 A, T _J = -40°C to +125°C	-2		+2	%
Adjustable Output Voltage	V _{ADJ}	louτ = 100 mA	0.495	0.5	0.505	V
Accuracy (ADP1741) ²		$I_{OUT} = 10 \text{ mA to } 2 \text{ A}$	0.492		0.508	V
		$10 \text{ mA} < I_{OUT} < 2 \text{ A}, T_J = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}$	0.490		0.510	V
LINE REGULATION	$\Delta V_{OUT} / \Delta V_{IN}$	$V_{IN} = (V_{OUT} + 0.4 V)$ to 3.6 V, $T_J = -40^{\circ}C$ to $+125^{\circ}C$	-0.3		+0.3	%/V
LOAD REGULATION ³	ΔVουτ/ΔΙουτ	$I_{OUT} = 10 \text{ mA to } 2 \text{ A}, T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$			0.5	%/A
DROPOUT VOLTAGE ⁴		$I_{OUT} = 100 \text{ mA}, V_{OUT} \ge 1.8 \text{ V}$		10	0.0	mV
	• DROPOUT	$I_{OUT} = 100 \text{ mA}, V_{OUT} \ge 1.8 \text{ V}, T_J = -40^{\circ}\text{C to} + 125^{\circ}\text{C}$		10	18	mV
		$I_{OUT} = 2 \text{ A}, V_{OUT} \ge 1.8 \text{ V}$		160	10	mV
		$I_{OUT} = 2 \text{ A}, V_{OUT} \ge 1.8 \text{ V}, T_J = -40^{\circ}\text{C to} + 125^{\circ}\text{C}$		100	280	mV
START-UP TIME ⁵	t _{start-up}	$C_{ss} = 0 \text{ nF}, I_{OUT} = 10 \text{ mA}$		200	200	μs
Shart of time	CSTART-OP	$C_{ss} = 10 \text{ nF}, I_{OUT} = 10 \text{ mA}$		5.2		ms
CURRENT-LIMIT THRESHOLD ⁶	ILIMIT		2.4	3	5	A
THERMAL SHUTDOWN	- 2000				5	
Thermal Shutdown Threshold	TS _{SD}	T₁ rising		150		°C
Thermal Shutdown Hysteresis	TS _{SD-HYS}			15		°C
PG OUTPUT LOGIC LEVEL	1350-115			15		C
PG Output Logic High	PGHIGH	$1.6 \text{ V} \le \text{V}_{\text{IN}} \le 3.6 \text{ V}$, $I_{\text{OH}} < 1 \ \mu\text{A}$	1.0			v
PG Output Logic Low	P GHIGH PGLOW	$1.6 \text{ V} \le V_{\text{IN}} \le 3.6 \text{ V}, \text{ IoH} < 1 \mu\text{A}$ $1.6 \text{ V} \le V_{\text{IN}} \le 3.6 \text{V}, \text{IoH} < 2 \text{mA}$	1.0		0.4	v
PG Output Delay from EN	F GLOW	$1.6 \text{ V} \le V_{\text{IN}} \le 3.6 \text{ V}, \text{ for } < 2.0 \text{ F}$ $1.6 \text{ V} \le V_{\text{IN}} \le 3.6 \text{ V}, \text{ Css} = 10 \text{ nF}$		5.5	0.4	-
Transition, Low to High		$1.0 \text{ V} \leq \text{VIN} \leq 3.0 \text{ V}, \text{C}_{SS} = 1011\text{F}$		5.5		ms
PG OUTPUT THRESHOLD						
Output Voltage Falling	PG _{FALL}	$1.6 V \le V_{IN} \le 3.6 V$		-10		%
Output Voltage Rising	PGRISE	$1.6 \text{ V} \le V_{\text{IN}} \le 3.6 \text{ V}$		-6.5		%
EN INPUT	I GINDE			0.5		70
EN Input Logic High	VIH	$1.6 \text{ V} \le \text{V}_{\text{IN}} \le 3.6 \text{ V}$	1.2			v
EN Input Logic Low	VIL	$1.6 V \le V_{IN} \le 3.6 V$			0.4	v
EN Input Leakage Current	VIL VI-LEAKAGE	EN = VIN or GND		0.1	0. 4 1	μA
UNDERVOLTAGE LOCKOUT	UVLO			0.1	•	P/ 1
Input Voltage Rising	UVLO				1.58	v
Input Voltage Falling			1.25		0.1	v
			1.20	100		
Hysteresis	UVLOHYS	161/21/2261/	0.6		1 2	mV
SOFT START CURRENT		$1.6 V \le V_{IN} \le 3.6 V$	0.6	0.9	1.2	μA
ADJ INPUT BIAS CURRENT (ADP1741)	ADJ _{I-BIAS}	$1.6 \text{ V} \le V_{IN} \le 3.6 \text{ V}, T_J = -40^{\circ}\text{C} \text{ to} + 125^{\circ}\text{C}$		10	150	nA

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
SENSE INPUT BIAS CURRENT (ADP1740)	SNS _{I-BIAS}	$1.6 \text{ V} \le \text{V}_{\text{IN}} \le 3.6 \text{ V}$		10		μA
OUTPUT NOISE	OUT _{NOISE}	10 Hz to 100 kHz, V _{OUT} = 0.75 V		23		μV rms
		10 Hz to 100 kHz, V _{OUT} = 2.5 V		65		μV rms
POWER SUPPLY REJECTION RATIO	PSRR	$V_{IN} = V_{OUT} + 1 V$, $I_{OUT} = 10 mA$				
		1 kHz, V _{OUT} = 0.75 V		65		dB
		1 kHz, V _{OUT} = 2.5 V		56		dB
		$10 \text{ kHz}, V_{OUT} = 0.75 \text{ V}$		65		dB
		10 kHz, V _{OUT} = 2.5 V		56		dB
		$100 \text{ kHz}, V_{\text{OUT}} = 0.75 \text{ V}$		54		dB
		100 kHz, V _{OUT} = 2.5 V		51		dB

¹ Minimum output load current is 500 µA.

² Accuracy when VOUT is connected directly to ADJ. When VOUT voltage is set by external feedback resistors, absolute accuracy in adjust mode depends on the tolerances of the resistors used.

³ Based on an endpoint calculation using 10 mA and 2 A loads. See Figure 6 for typical load regulation performance. ⁴ Dropout voltage is defined as the input to output voltage differential when the input voltage is set to the nominal output voltage. This applies only to output voltages

above 1.6 V.

 $^{\scriptscriptstyle 5}$ Start-up time is defined as the time between the rising edge of EN to V_{OUT} being at 95% of its nominal value.

⁶ Current-limit threshold is defined as the current at which the output voltage drops to 90% of the specified typical value. For example, the current limit for a 1.0 V output voltage is defined as the current that causes the output voltage to drop to 90% of 1.0 V, or 0.9 V.

INPUT AND OUTPUT CAPACITOR, RECOMMENDED SPECIFICATIONS

Table 2.

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
MINIMUM INPUT AND OUTPUT CAPACITANCE ¹	Сміл	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	3.3			μF
CAPACITOR ESR	R _{ESR}	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	0.001		0.1	Ω

¹ The minimum input and output capacitance should be greater than 3.3 µF over the full range of operating conditions. The full range of operating conditions in the application must be considered during capacitor selection to ensure that the minimum capacitance specification is met. X7R and X5R type capacitors are recommended; Y5V and Z5U capacitors are not recommended for use with this LDO.

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
VIN to GND	–0.3 V to +4.0 V
VOUT to GND	-0.3 V to V _{IN}
EN to GND	-0.3 V to V _{IN}
SS to GND	-0.3 V to V _{IN}
PG to GND	–0.3 V to +4.0 V
SENSE/ADJ to GND	-0.3 V to V _{IN}
Storage Temperature Range	–65°C to +150°C
Junction Temperature Range	-40°C to +125°C
Junction Temperature	150°C
Soldering Conditions	JEDEC J-STD-020

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL DATA

Absolute maximum ratings apply only individually, not in combination. The ADP1740/ADP1741 may be damaged when junction temperature limits are exceeded. Monitoring ambient temperature does not guarantee that the junction temperature is within the specified temperature limits. In applications with high power dissipation and poor PCB thermal resistance, the maximum ambient temperature may need to be derated. In applications with moderate power dissipation and low PCB thermal resistance, the maximum ambient temperature can exceed the maximum limit as long as the junction temperature is within specification limits.

The junction temperature (T_I) of the device is dependent on the ambient temperature (T_A) , the power dissipation of the device (P_D) , and the junction-to-ambient thermal resistance of the package (θ_{IA}) . T_I is calculated using the following formula:

 $T_J = T_A + (P_D \times \theta_{\rm JA})$

The junction-to-ambient thermal resistance (θ_{IA}) of the package is based on modeling and calculation using a 4-layer board. The junction-to-ambient thermal resistance is highly dependent on the application and board layout. In applications where high maximum power dissipation exists, close attention to thermal board design is required. The value of θ_{IA} may vary, depending on PCB material, layout, and environmental conditions. The specified values of θ_{IA} are based on a 4-layer, 4 in × 3 in circuit board. Refer to JEDEC JESD51-7 for detailed information about board construction. For more information, see the AN-772 Application Note, *A Design and Manufacturing Guide for the Lead Frame Chip Scale Package (LFCSP)*, at www.analog.com.

 Ψ_{JB} is the junction-to-board thermal characterization parameter with units of °C/W. Ψ_{JB} of the package is based on modeling and calculation using a 4-layer board. The JEDEC JESD51-12 document, *Guidelines for Reporting and Using Electronic Package Thermal Information*, states that thermal characterization parameters are not the same as thermal resistances. Ψ_{JB} measures the component power flowing through multiple thermal paths rather than through a single path, as in thermal resistance (θ_{JB}). Therefore, Ψ_{JB} thermal paths include convection from the top of the package, as well as radiation from the package, factors that make Ψ_{JB} more useful in real-world applications. Maximum junction temperature (T_J) is calculated from the board temperature (T_B) and the power dissipation (P_D) using the following formula:

 $T_J = T_B + (P_D \times \Psi_{\rm JB})$

Refer to the JEDEC JESD51-8 and JESD51-12 documents for more detailed information about $\Psi_{\text{JB}}.$

THERMAL RESISTANCE

 θ_{JA} and Ψ_{JB} are specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 4. Thermal Resistance

Package Type	θ」Α	Ψ _{JB}	Unit
16-Lead LFCSP with Exposed Pad	42	25.5	°C/W

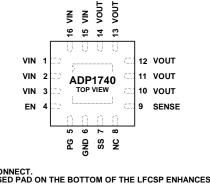
ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

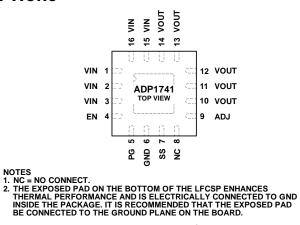
Table 5. Pin Function Descriptions

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS



NOTES 1. NC = NO CONNECT. 2. THE EXPOSED PAD ON THE BOTTOM OF THE LFCSP ENHANCES THERMAL PERFORMANCE AND IS ELECTRICALLY CONNECTED TO GND INSIDE THE PACKAGE. IT IS RECOMMENDED THAT THE EXPOSED PAD BE CONNECTED TO THE GROUND PLANE ON THE BOARD.





7081-004

Figure 4. ADP1741 Pin Configuration

Pin No. **ADP1740 ADP1741** Mnemonic Description 1, 2, 3, 15, 16 1, 2, 3, 15, 16 Regulator Input Supply. Bypass VIN to GND with a 4.7 µF or greater capacitor. Note that all VIN five VIN pins must be connected to the source supply. Enable Input. Drive EN high to turn on the regulator; drive it low to turn off the regulator. For 4 4 ΕN automatic startup, connect EN to VIN. 5 PG Power-Good Output. This open-drain output requires an external pull-up resistor to VIN. If 5 the part is in shutdown mode, current-limit mode, or thermal shutdown, or if it falls below 90% of the nominal output voltage, the PG pin immediately transitions low. 6 6 GND Ground. 7 SS 7 Soft Start Pin. A capacitor connected to this pin determines the soft start time. 8 8 NC Not Connected. No internal connection. Sense Input. This pin measures the actual output voltage at the load and feeds it to the error SENSE 9 amplifier. Connect the SENSE pin as close to the load as possible to minimize the effect of IR drop between the regulator output and the load. 9 ADJ Adjust Pin. A resistor divider from VOUT to ADJ sets the output voltage. Regulated Output Voltage. Bypass VOUT to GND with a 4.7 µF or greater capacitor. Note that 10, 11, 12, 10, 11, 12, VOUT 13, 14 13, 14 all five VOUT pins must be connected to the load. EP EΡ Exposed The exposed pad on the bottom of the LFCSP enhances thermal performance and is pad electrically connected to GND inside the package. It is recommended that the exposed pad be connected to the ground plane on the board.

TYPICAL PERFORMANCE CHARACTERISTICS

 V_{IN} = 1.9 V, V_{OUT} = 1.5 V, I_{OUT} = 100 mA, C_{IN} = C_{OUT} = 4.7 μ F, T_A = 25°C, unless otherwise noted.

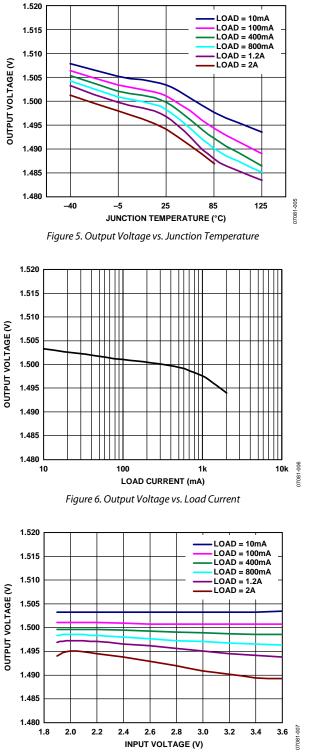
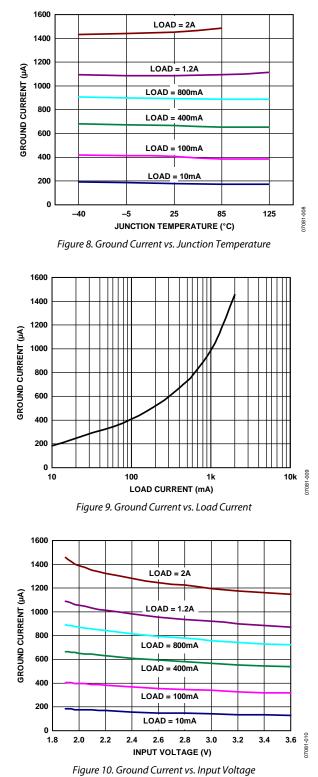


Figure 7. Output Voltage vs. Input Voltage



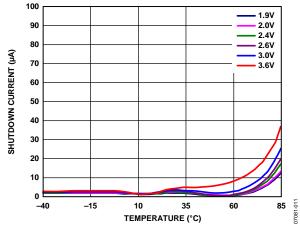


Figure 11. Shutdown Current vs. Temperature at Various Input Voltages

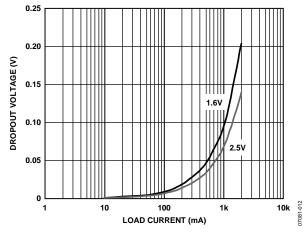
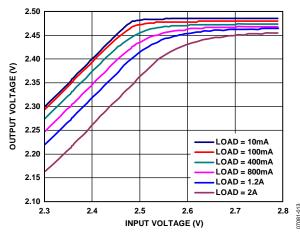
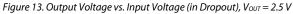


Figure 12. Dropout Voltage vs. Load Current, Vout = 1.6 V, 2.5 V





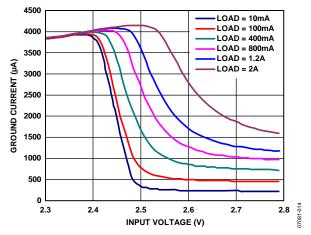
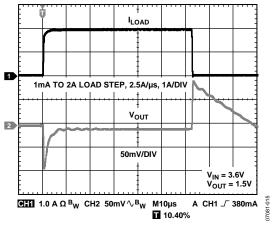
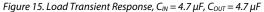
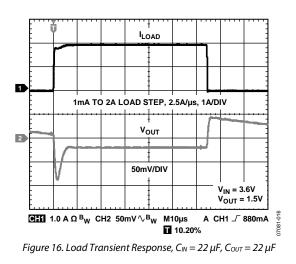


Figure 14. Ground Current vs. Input Voltage (in Dropout), Vout = 2.5 V







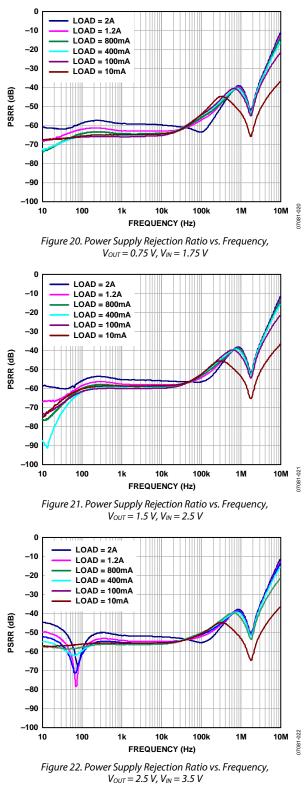
Data Sheet

VIN 3V TO 3.5V INPUT VOLTAGE STEP, 2V/µs VOUT 2 5mV/DIV V_{OUT} = 1.5V C_{IN} = C_{OUT} = 4.7μF 1 **611** 500mV $^{\rm B}W$ CH2 5mV $^{\rm A}V$ 7081-012 M10µs A CH4 / 800mV **1** 9.40% Figure 17. Line Transient Response, Load Current = 2 A 70 2.5V 60 50 NOISE (µV rms) 40 1.5V 30 0.75V 20 10 0 07081-018 0.0001 0.001 0.01 0.1 1 10 LOAD CURRENT (A) Figure 18. Noise vs. Load Current and Output Voltage 10 NOISE SPECTRAL DENSITY (µV/\Hz) 1 .5V .5V 0.1 0.75 0.01 -019 1k

10k

100k

7081



10

100

FREQUENCY (Hz)

Figure 19. Noise Spectral Density vs. Output Voltage, ILOAD = 10 mA

ADP1740/ADP1741

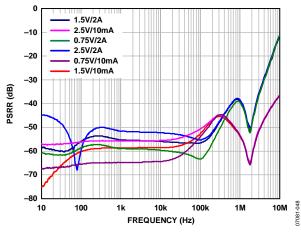


Figure 23. Power Supply Rejection Ratio vs. Frequency and Output Voltage

Rev. H | Page 10 of 20

THEORY OF OPERATION

The ADP1740/ADP1741 are low dropout linear regulators that use an advanced, proprietary architecture to provide high power supply rejection ratio (PSRR) and excellent line and load transient response with only a small 4.7 μ F ceramic output capacitor. Both devices operate from a 1.6 V to 3.6 V input rail and provide up to 2 A of output current. Supply current in shutdown mode is typically 2 μ A.

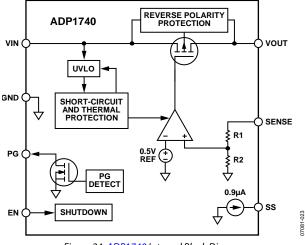


Figure 24. ADP1740 Internal Block Diagram

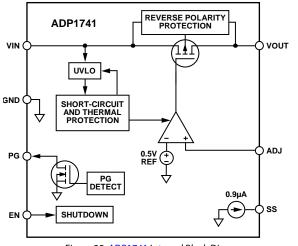


Figure 25. ADP1741 Internal Block Diagram

Internally, the ADP1740/ADP1741 consist of a reference, an error amplifier, a feedback voltage divider, and a PMOS pass transistor. Output current is delivered via the PMOS pass transistor, which is controlled by the error amplifier. The error amplifier compares the reference voltage with the feedback voltage from the output and amplifies the difference. If the feedback voltage is lower than the reference voltage, the gate of the PMOS device is pulled lower, allowing more current to pass and increasing the output voltage. If the feedback voltage is higher than the reference voltage, the gate of the PMOS device is pulled higher, allowing less current to pass and decreasing the output voltage. The ADP1740 is available in seven fixed output voltage options from 0.75 V to 2.5 V. The ADP1740 allows for connection of an external soft start capacitor, which controls the output voltage ramp during startup. The ADP1741 is an adjustable version with an output voltage that can be set to a value from 0.75 V to 3.3 V by an external voltage divider. Both devices are controlled by an enable pin (EN).

SOFT START FUNCTION

For applications that require a controlled startup, the ADP1740/ ADP1741 provide a programmable soft start function. The programmable soft start is useful for reducing inrush current upon startup and for providing voltage sequencing. To implement soft start, connect a small ceramic capacitor from SS to GND. Upon startup, a 0.9 µA current source charges this capacitor. The ADP1740/ADP1741 start-up output voltage is limited by the voltage at SS, providing a smooth ramp-up to the nominal output voltage. The soft start time is calculated as follows:

$$t_{SS} = V_{REF} \times (C_{SS}/I_{SS}) \tag{1}$$

where:

tss is the soft start period.

 V_{REF} is the 0.5 V reference voltage.

*C*_{SS} is the soft start capacitance from SS to GND.

 I_{SS} is the current sourced from SS (0.9 μ A).

When the ADP1740/ADP1741 are disabled (using the EN pin), the soft start capacitor is discharged to GND through an internal 100 Ω resistor.

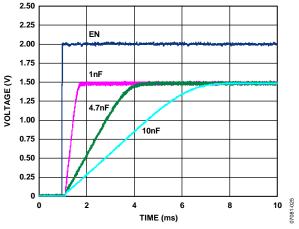
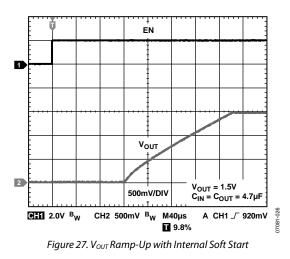


Figure 26. VOUT Ramp-Up with External Soft Start Capacitor

024



ADJUSTABLE OUTPUT VOLTAGE (ADP1741)

The output voltage of the ADP1741 can be set over a 0.75 V to 3.3 V range. The output voltage is set by connecting a resistive voltage divider from VOUT to ADJ. The output voltage is calculated using the following equation:

$$V_{OUT} = 0.5 \text{ V} \times (1 + R1/R2)$$
(2)

where:

R1 is the resistor from VOUT to ADJ. R2 is the resistor from ADJ to GND.

The maximum bias current into ADJ is 150 nA, so to achieve less than 0.5% error due to the bias current, use values less than 60 k Ω for R2.

ENABLE FEATURE

The ADP1740/ADP1741 use the EN pin to enable and disable the VOUT pins under normal operating conditions. As shown in Figure 28, when a rising voltage on EN crosses the active threshold, VOUT turns on. When a falling voltage on EN crosses the inactive threshold, VOUT turns off.

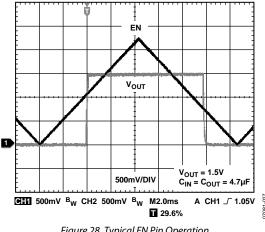
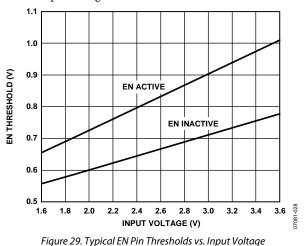


Figure 28. Typical EN Pin Operation

As shown in Figure 28, the EN pin has hysteresis built in. This hysteresis prevents on/off oscillations that can occur due to noise on the EN pin as it passes through the threshold points.

The EN pin active/inactive thresholds are derived from the VIN voltage. Therefore, these thresholds vary with changing input voltage. Figure 29 shows typical EN active/inactive thresholds when the input voltage varies from 1.6 V to 3.6 V.



POWER-GOOD FEATURE

The ADP1740/ADP1741 provide a power-good pin, PG, to indicate the status of the output. This open-drain output requires an external pull-up resistor to VIN. If the part is in shutdown mode, current-limit mode, or thermal shutdown, or if it falls below 90% of the nominal output voltage, the powergood pin (PG) immediately transitions low. During soft start, the rising threshold of the power-good signal is 93.5% of the nominal output voltage.

The open-drain output is held low when the ADP1740/ADP1741 have sufficient input voltage to turn on the internal PG transistor. An optional soft start delay can be detected. The PG transistor is terminated via a pull-up resistor to VOUT or VIN.

Power-good accuracy is 93.5% of the nominal regulator output voltage when this voltage is rising, with a 90% trip point when this voltage is falling. Regulator input voltage brownouts or glitches trigger power no-good if Vout falls below 90%.

A normal power-down triggers power no-good when VOUT drops below 90%.

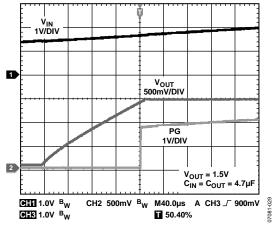


Figure 30. Typical PG Behavior vs. Vout, VIN Rising (Vout = 1.5 V)

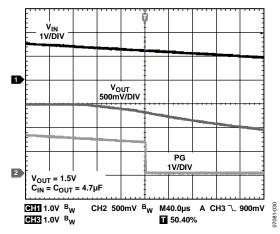


Figure 31. Typical PG Behavior vs. VOUT, VIN Falling (VOUT = 1.5 V)

REVERSE CURRENT PROTECTION FEATURE

The ADP1740/ADP1741 have additional circuitry to protect against reverse current flow from VOUT to VIN. For a typical LDO with a PMOS pass device, there is an intrinsic body diode between VIN and VOUT. When V_{IN} is greater than V_{OUT} , this diode is reverse-biased. If V_{OUT} is greater than V_{IN} , the intrinsic diode becomes forward-biased and conducts current from VOUT to VIN, potentially causing destructive power dissipation. The reverse current protection circuitry detects when V_{OUT} is greater than V_{IN} and reverses the direction of the intrinsic diode connection, reverse-biasing the diode. The gate of the PMOS pass device is also connected to VOUT, keeping the device off. Figure 32 shows a plot of the reverse current vs. the V_{OUT} to V_{IN} differential.

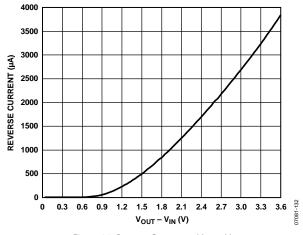
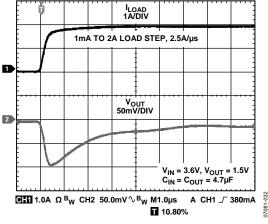


Figure 32. Reverse Current vs. VOUT - VIN

APPLICATIONS INFORMATION CAPACITOR SELECTION

Output Capacitor

The ADP1740/ADP1741 are designed for operation with small, space-saving ceramic capacitors, but they function with most commonly used capacitors as long as care is taken with regard to the effective series resistance (ESR) value. The ESR of the output capacitor affects the stability of the LDO control loop. A minimum of 3.3 μ F capacitance with an ESR of 100 m Ω or less is recommended to ensure the stability of the ADP1740/ADP1741. Transient response to changes in load current is also affected by output capacitance. Using a larger value of output capacitance improves the transient response of the ADP1740/ADP1741 to large changes in load current. Figure 33 and Figure 34 show the transient responses for output capacitance values of 4.7 μ F and 22 μ F, respectively.





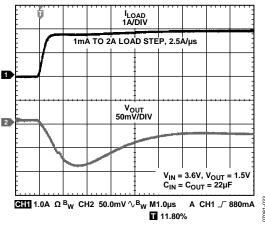


Figure 34. Output Transient Response, $C_{OUT} = 22 \,\mu F$

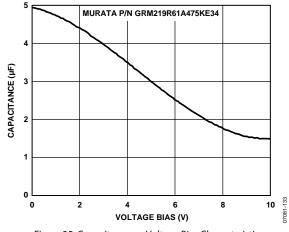
Input Bypass Capacitor

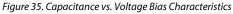
Connecting a 4.7 μ F capacitor from the VIN pin to GND reduces the circuit sensitivity to printed circuit board (PCB) layout, especially when long input traces or high source impedance are encountered. If output capacitance greater than 4.7 μ F is required, it is recommended that the input capacitor be increased to match it.

Input and Output Capacitor Properties

Any good quality ceramic capacitors can be used with the ADP1740/ADP1741, as long as they meet the minimum capacitance and maximum ESR requirements. Ceramic capacitors are manufactured with a variety of dielectrics, each with different behavior over temperature and applied voltage. Capacitors must have a dielectric adequate to ensure the minimum capacitance over the necessary temperature range and dc bias conditions. X5R or X7R dielectrics with a voltage rating of 6.3 V or 10 V are recommended. Y5V and Z5U dielectrics are not recommended, due to their poor temperature and dc bias characteristics.

Figure 35 shows the capacitance vs. voltage bias characteristics of an 0805 case, 4.7 μ F, 10 V, X5R capacitor. The voltage stability of a capacitor is strongly influenced by the capacitor size and voltage rating. In general, a capacitor in a larger package or with a higher voltage rating exhibits better stability. The temperature variation of the X5R dielectric is approximately ±15% over the -40° C to +85°C temperature range and is not a function of package size or voltage rating.





Use Equation 3 to determine the worst-case capacitance, accounting for capacitor variation over temperature, component tolerance, and voltage.

$$C_{EFF} = C_{OUT} \times (1 - TEMPCO) \times (1 - TOL)$$
(3)

where:

 C_{EFF} is the effective capacitance at the operating voltage. *TEMPCO* is the worst-case capacitor temperature coefficient. *TOL* is the worst-case component tolerance. In this example, the worst-case temperature coefficient (TEMPCO) over -40° C to $+85^{\circ}$ C is assumed to be 15% for an X5R dielectric. The tolerance of the capacitor (TOL) is assumed to be 10%, and C_{OUT} = 4.46 μ F at 1.8 V, as shown in Figure 35.

Substituting these values in Equation 3 yields

 $C_{EFF} = 4.46 \ \mu\text{F} \times (1 - 0.15) \times (1 - 0.1) = 3.41 \ \mu\text{F}$

Therefore, the capacitor chosen in this example meets the minimum capacitance requirement of the LDO over temperature and tolerance at the chosen output voltage.

To guarantee the performance of the ADP1740/ADP1741, it is imperative that the effects of dc bias, temperature, and tolerances on the behavior of the capacitors be evaluated for each application.

UNDERVOLTAGE LOCKOUT

The ADP1740/ADP1741 have an internal undervoltage lockout circuit that disables all inputs and the output when the input voltage is less than approximately 1.58 V. This ensures that the ADP1740/ADP1741 inputs and the output behave in a predictable manner during power-up.

CURRENT-LIMIT AND THERMAL OVERLOAD PROTECTION

The ADP1740/ADP1741 are protected against damage due to excessive power dissipation by current-limit and thermal overload protection circuits. The ADP1740/ADP1741 are designed to reach current limit when the output load reaches 3 A (typical). When the output load exceeds 3 A, the output voltage is reduced to maintain a constant current limit.

Thermal overload protection is included, which limits the junction temperature to a maximum of 150°C (typical). Under extreme conditions (that is, high ambient temperature and power dissipation) when the junction temperature begins to rise above 150°C, the output is turned off, reducing the output current to zero. When the junction temperature drops below 135°C (typical), the output is turned on again and output current is restored to its nominal value.

Consider the case where a hard short from VOUT to ground occurs. At first, the ADP1740/ADP1741 reach current limit so that only 3 A is conducted into the short. If self-heating of the junction becomes great enough to cause its temperature to rise above 150°C, thermal shutdown activates, turning off the output and reducing the output current to zero. As the junction temperature cools and drops below 135°C, the output turns on and conducts 3 A into the short, again causing the junction temperature to rise above 150°C. This thermal oscillation between 135°C and 150°C causes a current oscillation between 3 A and 0 A that continues as long as the short remains at the output.

Current-limit and thermal overload protections are intended to protect the device against accidental overload conditions. For reliable operation, device power dissipation should be externally limited so that junction temperatures do not exceed 125°C.

THERMAL CONSIDERATIONS

To guarantee reliable operation, the junction temperature of the ADP1740/ADP1741 must not exceed 125°C. To ensure that the junction temperature stays below this maximum value, the user needs to be aware of the parameters that contribute to junction temperature changes. These parameters include ambient temperature, power dissipation in the power device, and thermal resistance between the junction and ambient air (θ_{JA}). The θ_{JA} value is dependent on the package assembly compounds used and the amount of copper to which the GND pin and the exposed pad (EP) of the package are soldered on the PCB. Table 6 shows typical θ_{JA} values for the 16-lead LFCSP for various PCB copper sizes. Table 7 shows typical Ψ_{JB} values for the 16-lead LFCSP.

Table 6. Typical θ_{JA} Values

Copper Size (mm ²)	θ _{JA} (°C/W), LFCSP
01	130
100	80
500	69
1000	54
6400	42

¹ Device soldered to minimum size pin traces.

Table 7. Typical Ψ_{IB} Values

Copper Size (mm ²)	Ψ _{JB} (°C/W) at 1 W
100	32.7
500	31.5
1000	25.5

The junction temperature of the ADP1740/ADP1741 can be calculated from the following equation:

$$T_J = T_A + (P_D \times \theta_{JA}) \tag{4}$$

where:

 T_A is the ambient temperature.

 P_D is the power dissipation in the die, given by

$$P_D = [(V_{IN} - V_{OUT}) \times I_{LOAD}] + (V_{IN} \times I_{GND})$$
(5)

where:

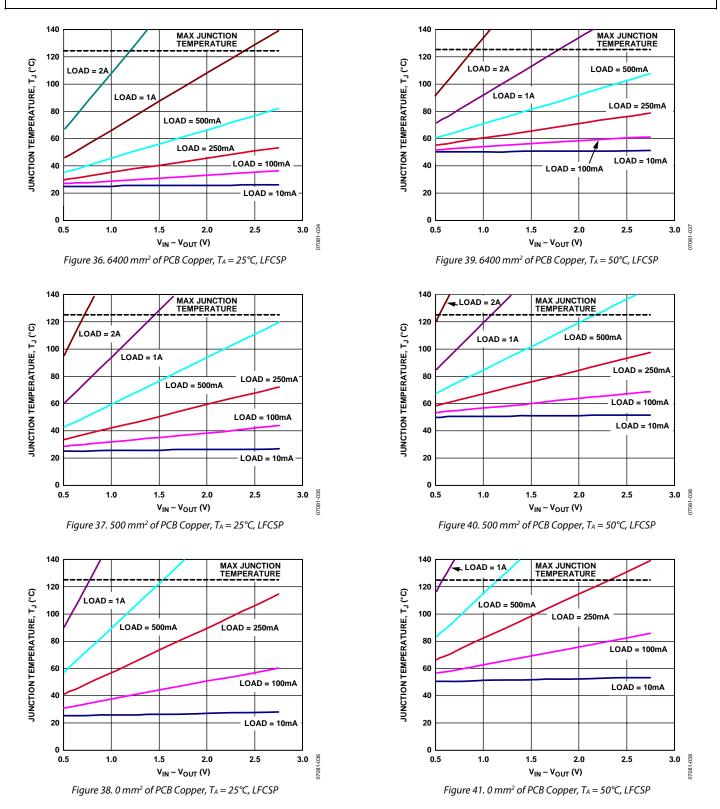
 V_{IN} and V_{OUT} are the input and output voltages, respectively. I_{LOAD} is the load current.

 I_{GND} is the ground current.

Power dissipation due to ground current is quite small and can be ignored. Therefore, the junction temperature equation can be simplified as follows:

$$T_J = T_A + \{ [(V_{IN} - V_{OUT}) \times I_{LOAD}] \times \theta_{JA} \}$$
(6)

As shown in Equation 6, for a given ambient temperature, inputto-output voltage differential, and continuous load current, a minimum copper size requirement exists for the PCB to ensure that the junction temperature does not rise above 125°C. Figure 36 through Figure 41 show junction temperature calculations for different ambient temperatures, load currents, V_{IN} to V_{OUT} differentials, and areas of PCB copper.



Data Sheet

ADP1740/ADP1741

In cases where the board temperature is known, the thermal characterization parameter, Ψ_{JB} , can be used to estimate the junction temperature rise. Maximum junction temperature (T_J) is calculated from the board temperature (T_B) and the power dissipation (P_D) using the following formula:

$$T_J = T_B + (P_D \times \Psi_{\rm JB}) \tag{7}$$

Figure 42 through Figure 45 show junction temperature calculations for different board temperatures, load currents, V_{IN} to V_{OUT} differentials, and areas of PCB copper.

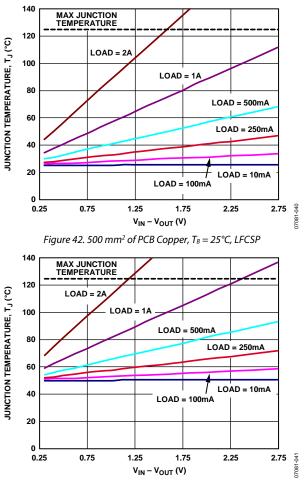
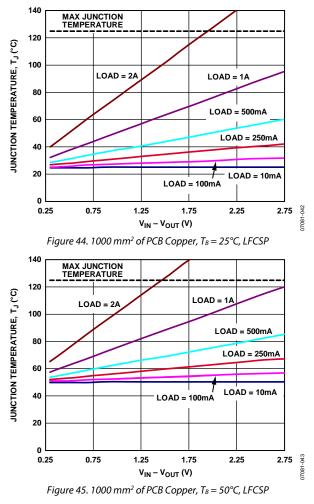


Figure 43. 500 mm² of PCB Copper, $T_B = 50^{\circ}$ C, LFCSP



PCB LAYOUT CONSIDERATIONS

Heat dissipation from the package can be improved by increasing the amount of copper attached to the pins of the ADP1740/ ADP1741. However, as shown in Table 6, a point of diminishing returns is eventually reached, beyond which an increase in the copper size does not yield significant heat dissipation benefits.

Here are a few general tips when designing PCBs:

- Place the input capacitor as close as possible to the VIN and GND pins.
- Place the output capacitor as close as possible to the VOUT and GND pins.
- Place the soft start capacitor close to the SS pin.
- Connect the load as close as possible to the VOUT and SENSE pins (ADP1740) or to the VOUT and ADJ pins (ADP1741).

Use of 0603 or 0805 size capacitors and resistors achieves the smallest possible footprint solution on boards where area is limited.

Data Sheet

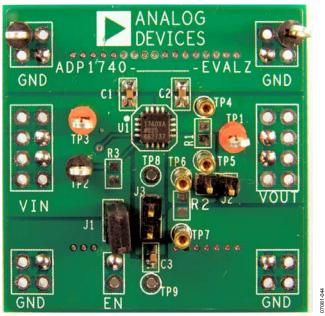


Figure 46. Evaluation Board

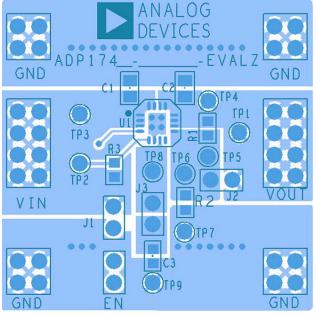


Figure 47. Typical Board Layout, Top Side

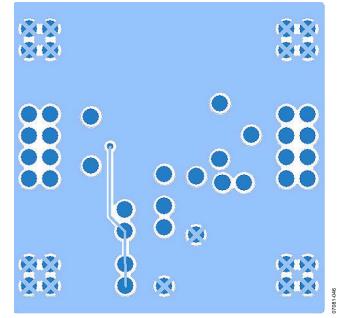


Figure 48. Typical Board Layout, Bottom Side

07081-045

OUTLINE DIMENSIONS

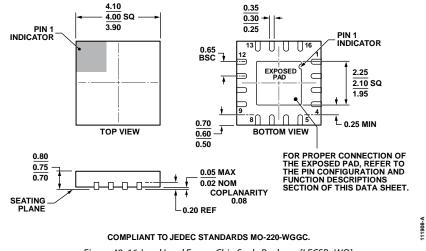


Figure 49. 16-Lead Lead Frame Chip Scale Package [LFCSP_WQ] 4 mm × 4 mm Body, Very Very Thin Quad (CP-16-23) Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Output Voltage (V)	Package Description	Package Option
ADP1740ACPZ-0.75R7	-40°C to +125°C	0.75	16-Lead LFCSP_WQ	CP-16-23
ADP1740ACPZ-1.0-R7	-40°C to +125°C	1.0	16-Lead LFCSP_WQ	CP-16-23
ADP1740ACPZ-1.1-R7	-40°C to +125°C	1.1	16-Lead LFCSP_WQ	CP-16-23
ADP1740ACPZ-1.2-R7	-40°C to +125°C	1.2	16-Lead LFCSP_WQ	CP-16-23
ADP1740ACPZ-1.3-R7	-40°C to +125°C	1.3	16-Lead LFCSP_WQ	CP-16-23
ADP1740ACPZ-1.5-R7	-40°C to +125°C	1.5	16-Lead LFCSP_WQ	CP-16-23
ADP1740ACPZ-1.8-R7	-40°C to +125°C	1.8	16-Lead LFCSP_WQ	CP-16-23
ADP1740ACPZ-2.5-R7	-40°C to +125°C	2.5	16-Lead LFCSP_WQ	CP-16-23
ADP1741ACPZ-R7	-40°C to +125°C	Adjustable, 0.75 to 3.3	16-Lead LFCSP_WQ	CP-16-23
ADP1740-1.5-EVALZ		1.5	Evaluation Board	
ADP1741-EVALZ		Adjustable	Evaluation Board	

 1 Z = RoHS Compliant Part.

NOTES

©2008–2015 Analog Devices, Inc. All rights reserved. Trademarks and registered trademarks are the property of their respective owners. D07081-0-1/15(H)



www.analog.com